

PHOTOJUNCTION CELL

GERMANIUM P-N ALLOY JUNCTION, SIDE-ON TYPE HAVING S-14 RESPONSE

For sound pickup-from-film, computer, punched-tape, and punched-card applications

DATA											
General:											
Spectral Response											
Shape. Circular Diameter (Minimum)											
Envelope Seals											
DIRECTION OF INCIDENT RADIATION: TOWARD RED DOT ON METAL COLLAR											
<u>*</u>											
NEXT TO + RED DOT ON METAL COLLAR Market M											
λ indicates that the primary characteristic of the element within the envelope symbol is designed to vary under the influence of light.											
Maximum Ratings, Absolute Values: 50 max. volts POLARIZING VOLTAGE											
Characteristics:											
Under conditions with polarizing voltage of 45 volts and ambient temperature of 25° C											
Min. Nedian Max.											
Sensitivity: Radiant, at 15000 angstroms 0.52 - $\mu a/\mu$											



7224

PHOTOJUNCTION CELL

								Min.	Nedian	Nax.	
Luminous#								-	14	_	ma/lumen
								0.5	0.7	_	μa/ft-c
Dark Current								_	-	35	, да
Photocurrent:											
Rise											. See Curve
I Decay	_	_	_	_	_	_	_				Saa Comment

For conditions where the light source is a tungsten-filament lamp operated at a color temperature of 2870° K.

† The value of illumination incident on the sensitive area is 73 footcandles.

OPERATING CONSIDERATIONS

The flexible leads of the 7224 are usually soldered to the circuit elements. Soldering of the leads may be made close to the glass stem provided care is taken to conduct excessive heat away from the lead seals. Otherwise, the heat of the soldering operation will crack the glass seals of the leads and damage the cell.

A clamp around the glass envelope may be used to hold the cell in position. However, care must be taken in clamping to avoid cracking the metal—collar—to—envelope sea!. Do not solder or braze directly to the metal collar of the cell.

The cell must be polarized by connecting the positive voltage to the lead indexed by the red dot on the metal collar.

The use of an optical system to focus the incident radiation onto the sensitive area of the cell is suggested, especially when the incident-radiation level is low. For high values of incident radiation, the entire side of the cell may be irradiated, but only that radiation intercepted by the sensitive area is effective in producing photocurrent.

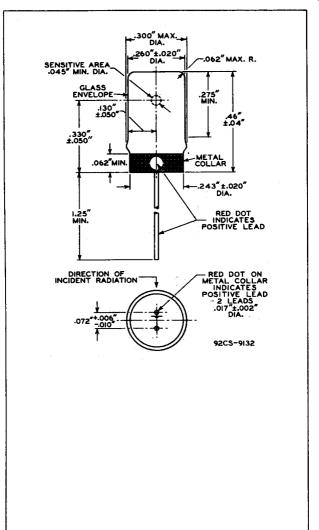
Exposure of the 7224 to intense radiation, such as focused sunlight, should be avoided under all conditions including the condition when no voltage is applied to the cell. Permanent damage to the cell may result if it is exposed to radiant energy so intense as to cause excessive heating of the cell.

With no radiation on the sensitive area of the cell, some dark current will flow across the junction. This current can be reduced, as shown in the accompanying curve, by operation of the cell at reduced ambient temperature.

SPECTRAL-SENSITIVITY CHARACTERISTIC of Photojunction Cell having S-14 Response is shown at the front of this Section



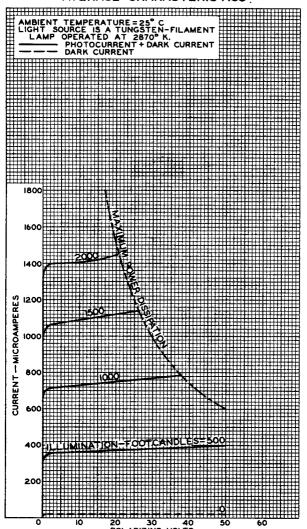
PHOTOJUNCTION CELL



722A

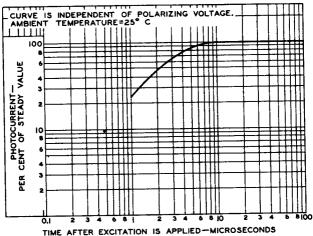


AVERAGE CHARACTERISTICS



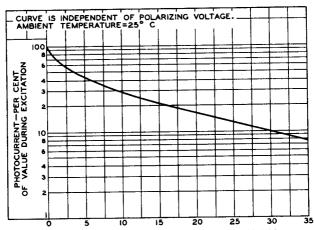


TYPICAL RISE CHARACTERISTIC



9205-9654

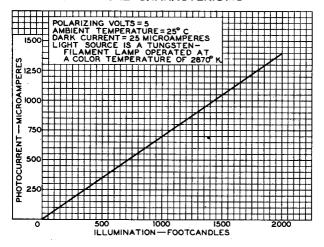
TYPICAL DECAY CHARACTERISTIC



R

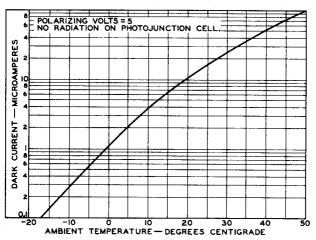


TYPICAL CHARACTERISTIC



92CS -9675

TYPICAL DARK-CURRENT CHARACTERISTIC



EQUIVALENT-NOISE-INPUT CHARACTERISTIC

